Ultrafast Beam Switching Using Coupled VCSEL

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Abstract

We propose a new approach to performing ultrafast beam switching using two coupled Vertical-Cavity Surface-Emitting Lasers (VCSELs). The strategy is demonstrated by numerical simulation, showing a beam switching of 10 degrees at 42 GHz.
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The ability to steer or switch propagation direction of a laser beam in a controllable way is very important for many applications, and especially for optical interconnect networks. Beam scanning and steering in edge emitting lasers have been realized using thermal control [1] and spatial phase controlling technique [2]. For optical interconnect application, all the well-known advantageous attributes of VCSELs make them especially appealing elements for such networks. For this reason, routers integrated together with VCSELs that can be controlled electronically are especially important to reduce the overall volume of interconnect network. By creating a phase shift in part of a VCSEL, it was demonstrated [3] that up to 2GHz beam switching can be achieved with maximum swing angle of about 3 degree.

In this paper, we propose a different approach to achieve ultrafast beam switching. Our approach is based on two VCSELs put in close proximity of each other. Strong coupling between the two VCSELs through carrier diffusion and through evanescent light produce ultrafast hopping of laser intensity between two VCSELs, resulting an ultrafast far-field switching between two directions. As an example, we demonstrate through extensive numerical simulation that two VCSELs placed about 1 micron apart between the edges can be switched at 42 GHz with maximum swing angles of 10 degree. We also demonstrate that the switching frequency and swing angle can be easily modified by adjusting coupling strength between the VCSELs.

Our simulation begins with the effective Bloch equations (EBEs) as applied to VCSEL simulation in [4]. This model has been used recently to simulate transverse mode dynamics in VCSELs [4]. The model consists of three coupled equations describing diffraction of laser field, carrier diffusion in the transverse plane, and optical gain and refractive index dynamics represented by an effective polarization. In our simulation, the EBE model is solved using finite-difference method in space and time domains directly without assuming a priori any mode structure or number of modes. At a given pumping (DC-bias) level, the simulation is performed over a period of several nanoseconds. The simulation
result is the space and time resolved complex field amplitude \( E(x,y,t) \), from which near- and far- field intensities are obtained. As an example, the simulation is performed for gain-guided VCSELs of 5.6 microns in diameter separated 0.8 microns edge-to-edge apart. In all the examples shown in the presentation, both VCSELs are biased slightly above threshold of individual VCSELs. Only one of them is modulated with a sinusoidal signal with an AC amplitude 1 percent of the DC bias.

\[
\begin{align*}
\text{Time (ns)} & \quad 94.16 & 94.18 & 94.20 & 94.22 & 94.24 & 94.26 \\
\text{Near-Field Intensity} & \quad 0 & 2 & 4 & 6 & 8 & 10 \\
\text{Far-Field Intensity} & \quad 0 & 2 & 4 & 6 & 8 & 10 \\
\end{align*}
\]

In the figure shown above we plot the time evolution of local laser intensities taken at centers of two VCSELs, as indicated by 'left' and 'right' in the figure. We see clearly that the peak intensities of the two VCSELs are performing anti-correlated oscillation at the modulation frequency of 42 GHz. In the bottom part of the figure (b), the far-field intensity at two angles separated by 6 degrees is plotted, showing again an anti-phase oscillation or beam switching between the two angles at 42 GHz. The maximum span of the switching angle is about 10 degrees. Another feature to be noted is that the far field intensity extremes appear when the near field intensities have equal value, showing a maximum constructive interference at an angle to the normal direction of the lasers. As demonstrated clearly in the figure, the beam switching at 42GHz is related to the hopping of peak intensity between two lasers. This hopping is caused by the coupling between the two VCSELs. To confirm this understanding, we varied the inter-VCSEL separation. When the separation decreases, the beam switching frequency increases, and vice versa. At 1 micron separation, the beam switching frequency is about 38 GHz. We also studied the influence of DC bias and found that the increase DC current can result an increase in modulation frequency. This is because the increased DC pumping increases the
spatial carrier overlap between the VCSELs. That, in turn, increases the effective coupling. It is straightforward to conclude that, whenever the coupling strength increases, the beam switching frequency will increase. This obviously gives some design flexibility to engineer the beam switching frequency and angles. For example, if farther separation is desired, an anti-guiding type of coupling can be adopted to maintain the strength of coupling and thus the switching frequency. VCSEL arrays based on anti-guiding coupling have been recently demonstrated by several groups. Directional beam switching using anti-guide-coupled VCSELs is currently under study and results will be reported elsewhere.

In Summary, we have proposed a new approach for ultrafast directional beam switching using coupled VCSELs. This approach is demonstrated to achieve over 40 GHz beam switching frequency. Furthermore, we point out that this approach is easy and flexible for design to achieve different switching speed and angle. This approach is likely to be useful for ultrafast optical networks at frequencies much higher than achievable with other approaches. Implementation of this approach for anti-guide coupled VCSELs and other related applications are currently under investigation.

References


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OUTLINE

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• Model and Simulation Equations
• Simulation Result
• Conclusion

Introduction

• Dynamic beam switching in VCSELs important for many applications, esp. in optical interconnect networks for beam routing
• Modulation and switching in semiconductor lasers typically limited by carrier-recombination time
• Directional beam switching in VCSELs at 2GHz has been realized (M.Wu et al, 1995,1997), but limited by RO and diffusion
• New approach based on coupled VCSELs proposed and demonstrated by numerical simulation showing over 40GHz beam switching with angle span around 10 degree
Model and Simulation Equations

Proposal: Using two VCSELs placed in closed proximity (-1 micron)

Demonstration: Numerical simulation of two VCSELs of 5.6 µm in diameter and placed -1 µm microns edge-to-edge apart

Simulation Result

* Total output displays oscillations with negligible amplitude, while output of individual lasers shows deep modulation
* Strong spectral response at modulated frequency around 42 GHz for individual laser output
Antiphase oscillation of near field leads to beam switching of far field at 42 GHz.
Snapshots of Near- and Far-Field Intensity

Modulation Response of 2-Coupled VCSELs (Gap=0.8, D=5.6)

Lower frequency response at 3.5 and 12 GHz, related to RO frequencies
Strong, narrow band response at 42 GHz corresponding to beam switching
Frequency Change with DC-Bias and Separation

![Frequency Change](image)

**Conclusion**

- Ultrafast beam switching at frequency > 40GHz with a maximum beam swing angle around 10 degree demonstrated by simulation
- Switching frequency not limited by slow processes such as RO or carrier diffusion, but controlled by coupling strength between the VCSELs, allowing engineering of both switching frequency and angle by adjusting coupling strength

**Future and on-going work**

- Beam switching using antiguide-coupled VCSELs
- 2D beam routing for 3D networking using following 2D arrangement:

![2D Arrangement](image)